

# **isc** Silicon NPN Power Transistor

# 2SD234

### DESCRIPTION

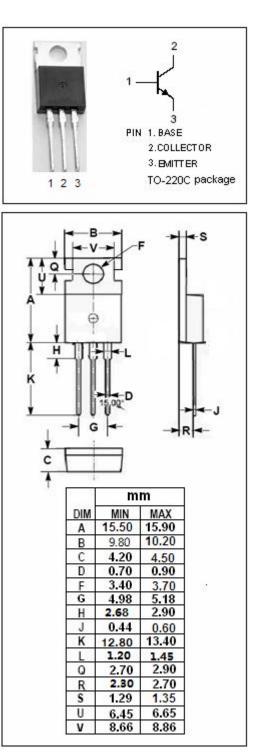
- Collector-Emitter Breakdown Voltage-: V<sub>(BR)CEO</sub>= 50V(Min)
- Low Collector-Emitter Saturation Voltage-: V<sub>CE(sat)</sub>= 1.2V(Max) @I<sub>C</sub>= 3.0A
- Complement to Type 2SB434
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

• Designed for audio power amplifier applications.

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>СВО</sub>	Collector-Base Voltage	60	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V	
V <sub>EBO</sub>	Emitter-Base Voltage	6	V	
lc	Collector Current-Continuous	3.0	А	
Pc	Collector Power Dissipation @ T <sub>a</sub> =25℃	1.5		
	Collector Power Dissipation @ $T_c$ =25 °C	25	W	
TJ	T <sub>J</sub> Junction Temperature 150		°C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	

## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)



isc website: <u>www.iscsemi.com</u>



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## **ELECTRICAL CHARACTERISTICS**

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =5mA; I <sub>B</sub> = 0	50			V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage	I <sub>C</sub> = 1mA; I <sub>E</sub> = 0	60			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.3A			1.2	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 3A; I <sub>B</sub> = 0.3A			1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 40V; I <sub>E</sub> = 0			10	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			10	μA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 5V	40		240	
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V, f <sub>test</sub> = 1MHz		90		pF
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 10V		3		MHz

### h<sub>FE</sub>Classifications

R	0	Y
40-80	70-140	120-240

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